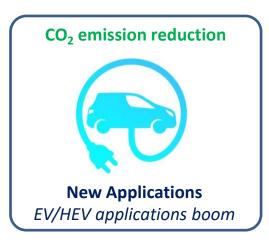


Introduction

Why to investigate the power module patent landscape?

Society





Impact

Power Module Patent Landscape



IP players
New IP players





Latest patents
Addressing the new
technical challenges



New interactions *IP collaborations & IP transfers across the EV/HEV supply chain*





Next-Generation Power Module

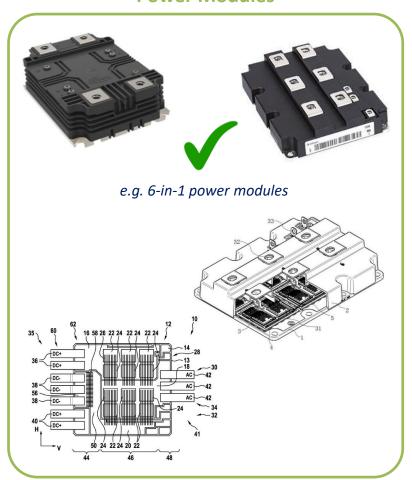
Patent Landscape Overview



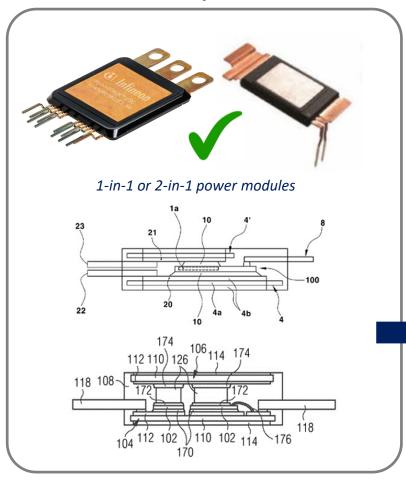
What is a power module patent?

A **power module** consists of an assembly of several power electronics components such as transistors and diodes in **a single package**:

Power Modules



"Discrete-like" power modules



Discrete Power Devices



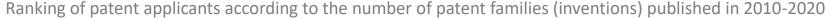
Small-size modules (usually looking like slim "card-like modules") have been identified as a trend in EV/HEV applications in the last couple of years.

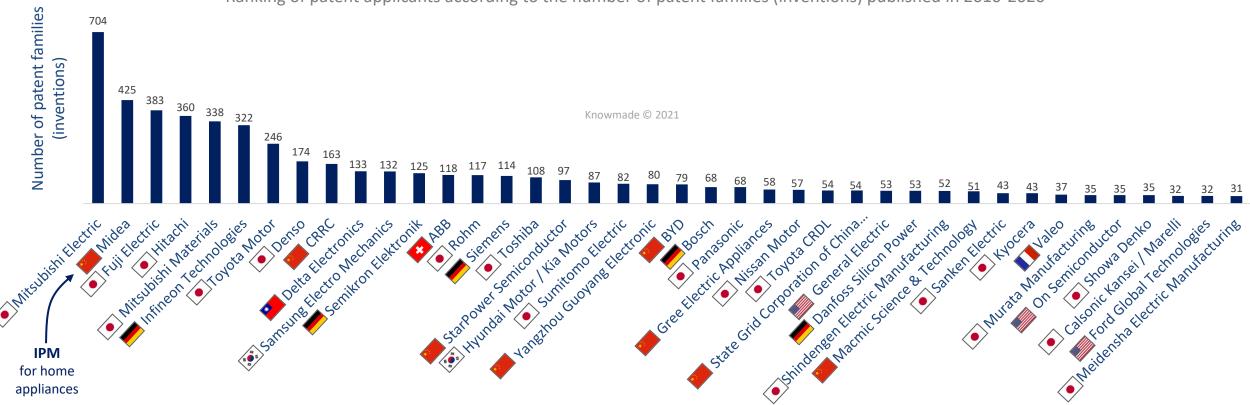


Main patent applicants



Next-Generation Power Modules



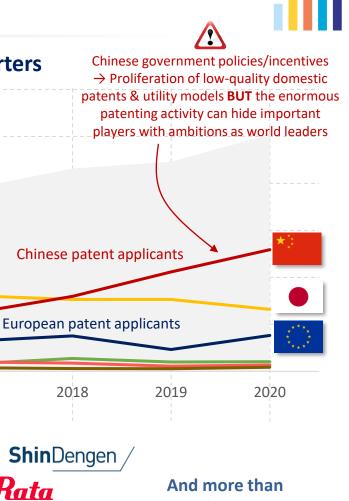


- The main players of the IGBT module market are well-positioned in terms of patenting activity.
- Japanese IP players domination over the last decade, competing mainly with European and Chinese IP players.



Time evolution of company headquarters







2010



2011



DENSO

NISSAN

2012



ROHM

2013



2014

Time evolution of patent publications by company headquarters





2016

All patent families



2017





SIEMENS

2015

Japanese patent applicants





2018



30 Chinese IP newcomers in 2019/2020







First publication year of patent families







Starting

IP activity

during

the last

decade

1200

1000

400

200

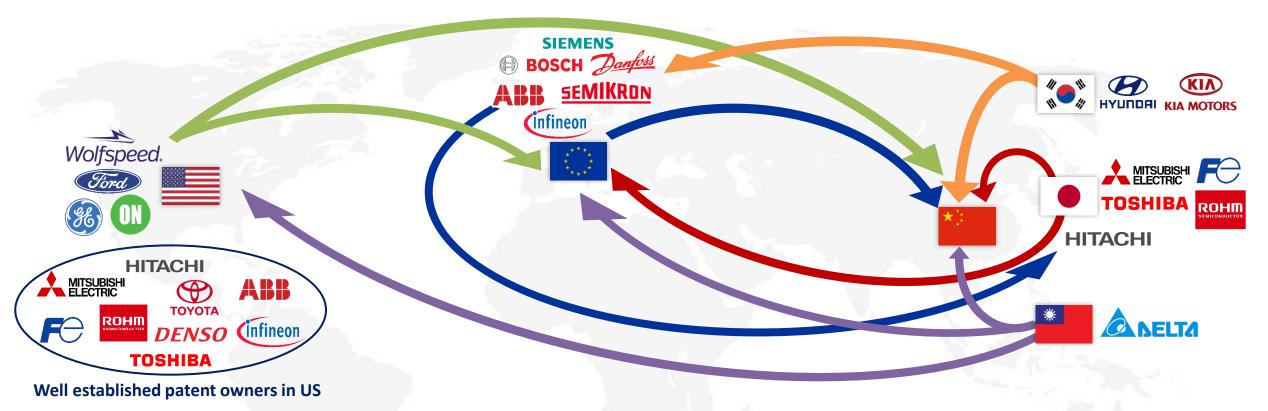
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Number of patent families

(inventions)

IP strategies of main patent applicants





Current IP strategy of main players (pending patent applications)





Next-Generation Power Module ide bandgap (SiC. Gal

Wide bandgap (SiC, GaN) & EV/HEV applications

Introduction

How to identify WBG power module patents or patents for EV/HEV applications?

■ Wide bandgap (WBG) power module patents are based on SiC or GaN power devices. However, this feature is not always explicitly or unambiguously given in patents:

WBG-focused patents

The invention is explicitly directed to WBG power devices (specific claims and/or specific embodiments for SiC and/or GaN)



WBG-related patents

The invention is explicitly applicable to WBG power devices but not only. In most cases, SiC and/or GaN technologies are mentioned in examples alongside other technologies such as Si, diamond, etc.

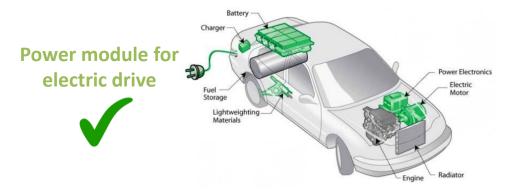


IGBT module & Generic module patents

The invention does not mention any preferred semiconductor technology (generic) or refers to non WBG technologies (mainly Silicon IGBT) in claims and/or embodiments.



■ EV/HEV application patents mention in the description a power module for an electric drive (e.g. traction/main inverter, drive motor), and/or a power module for use in EV charging of electric vehicles (e.g. charging stations).





Power module for EV charging

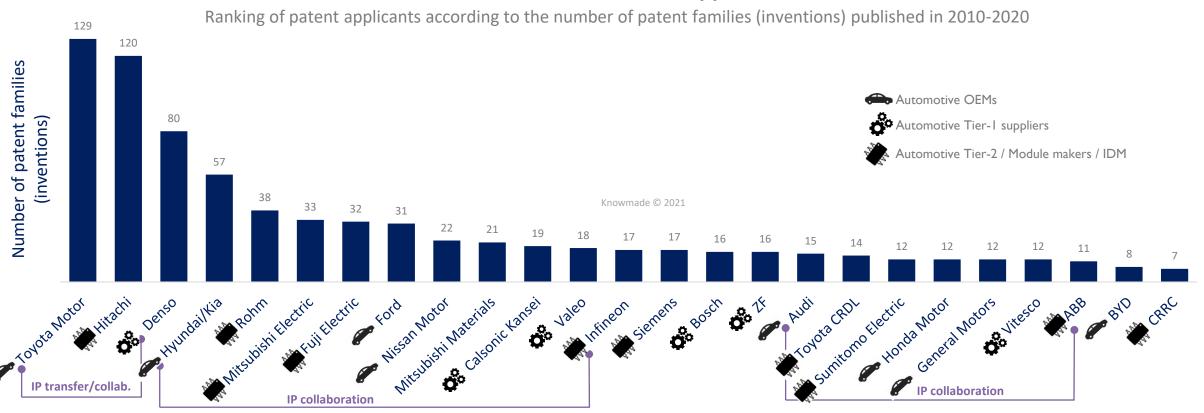




Main patent applicants



Power Modules for EV/HEV Applications

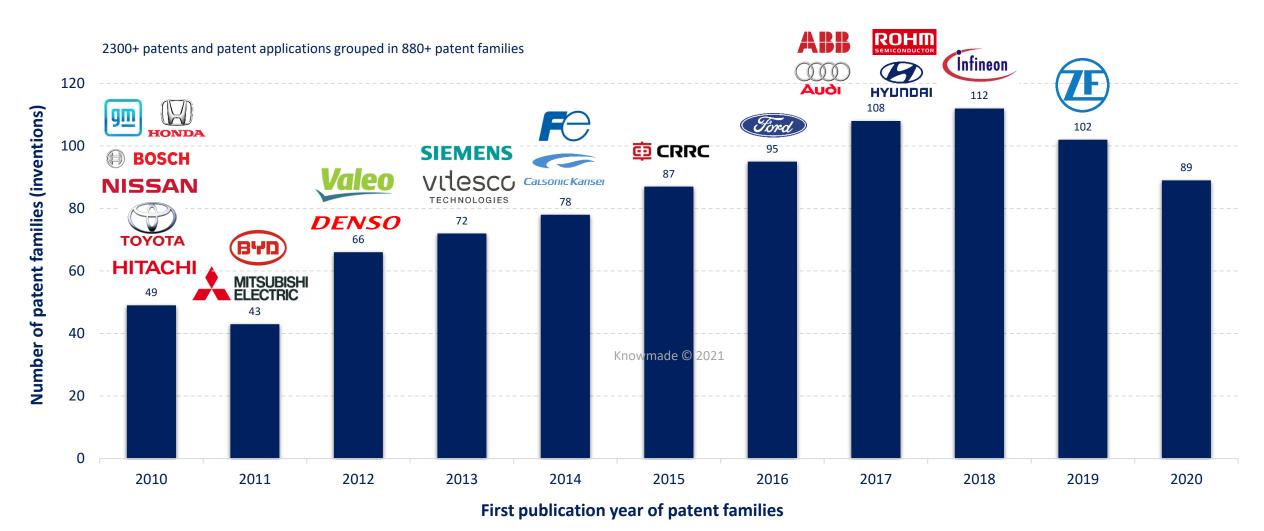




Timeline of patent publications

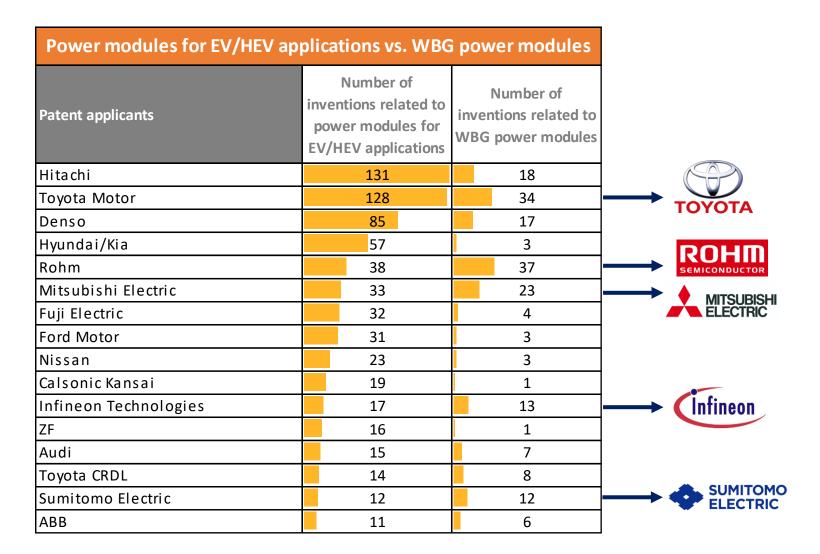


Time evolution of patent publications related to power modules for EV/HEV applications





EV/HEV applications vs. WBG power modules



IP players focusing on WBG power modules for EV/HEV applications



Focus on ABB/Audi collaboration



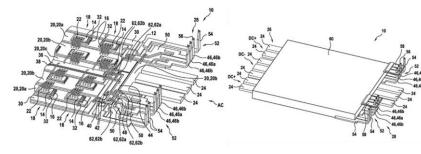




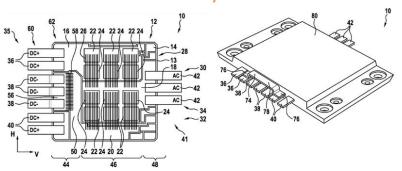
ABB & Audi has co-filed at least 70 patent applications between 2015 and 2019, grouped in 17 patent families (inventions), most of them for EV/HEV applications:

PATENTS

WBG power modules



Reduction of stray inductance

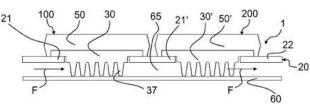


IP collaboration on power module



PATENTS

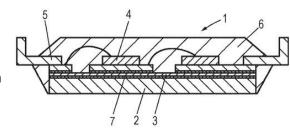
Heat dissipation



Context of the collaboration

- Hitachi announced in 2019 Audi will use its EV inverter based on Hitachi's compact DSC IGBT modules in Audi's first mass-produced EV model (e-tron)
- Audi made announcements in 2019-2020 of multiple partnerships with ABB for the development of the EV charging infrastructure
- In 2019, ABB disclosed a new SiC / Si module platform to address EV/HEV performance requirements
- In July 2020, Hitachi completed the acquisition of ABB Power Grids

Molding encapsulation





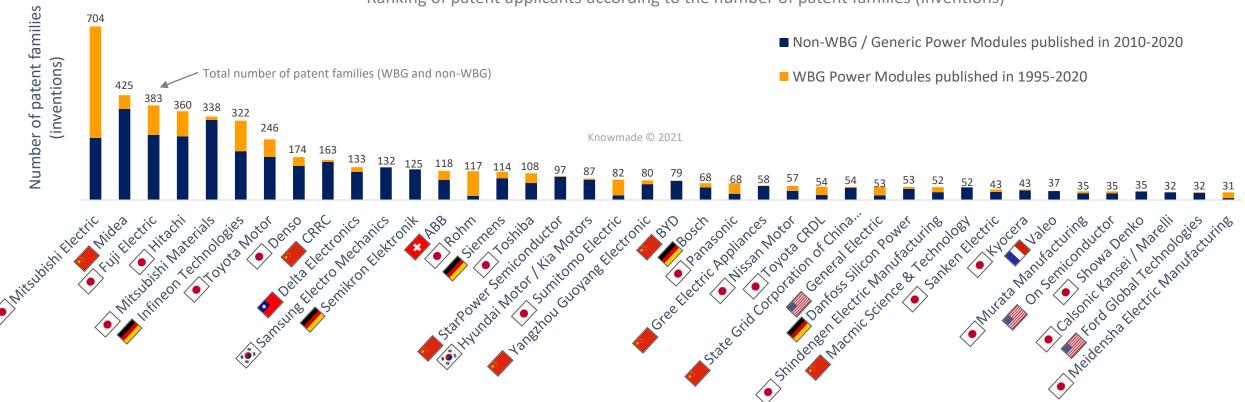
Wide Bandgap Power Modules

Main patent applicants



Next-Generation Power Modules



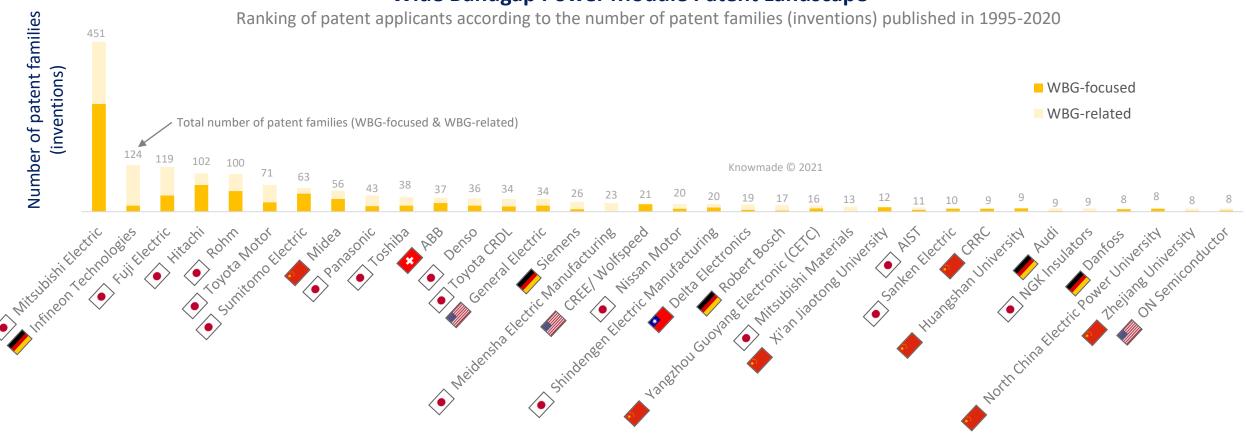




Main patent applicants



Wide Bandgap Power Module Patent Landscape



<u>WBG-focused patents:</u> The invention is explicitly directed to WBG power devices (**specific claims** and/or **specific embodiments** for SiC and/or GaN).

<u>WBG-related patents:</u> The invention is explicitly **applicable to WBG power devices but not only**. In most cases, SiC and/or GaN technologies are mentioned in examples alongside other technologies such as Si, diamond, etc.



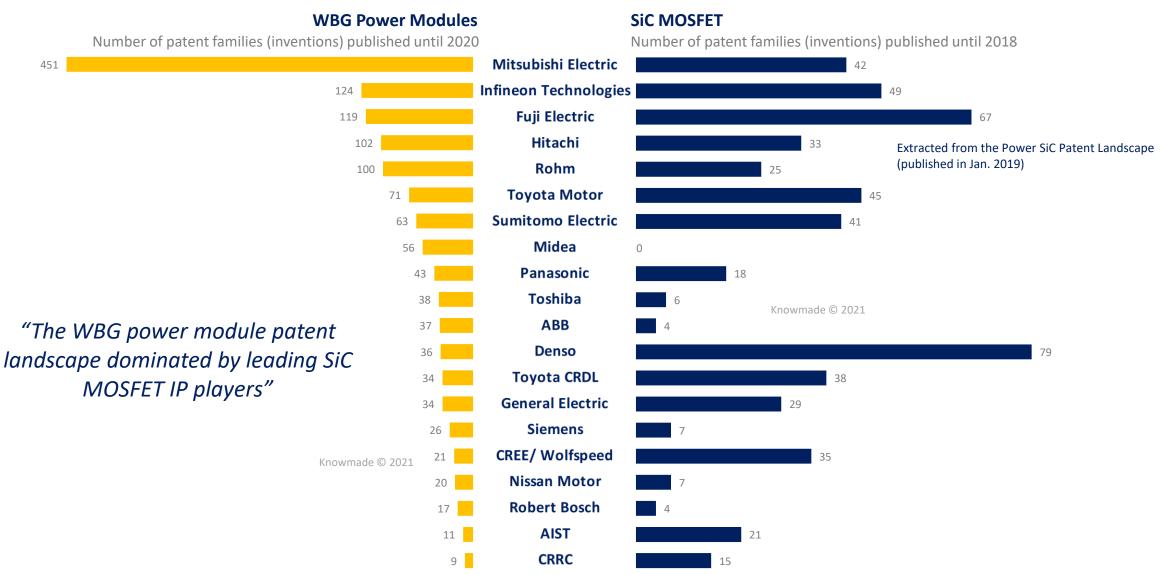
Timeline of patent publications (main IP players)



		First publication year of the family	
Patent applicant	Patent families	1995 1996 1996 1997 1998 1998 1999	
PANASONIC	43	1 1 1 2 2 2 2 2 2 6 4 10 5 2 1 1	
SUMITOMO ELECTRIC	63	1 6 5 5 5 2 1 2 6 4 9 3 3 6 2 3	SUMITOMO ELECTRIC
NISSAN MOTOR	20	2 2 5 4 1 1	
NFINEON TECHNOLOGIES	124	1 1 1 10 2 4 3 6 12 20 12 10 13 17 5 6	$ ightharpoon$ (acquired 20+ inventions from $ m {f I}$ in 2015
TOYOTA CRDL	34	1 3 5 2 2 1 1 1 2 1 1 2 12 1	
SIEMENS	26	2 1 1 2 1 1 4 2 3 5 2 2	→ SIEMENS
MEIDENSHA ELECTRIC MANUFACTURING	23	Farliact	/,
MITSUBISHI MATERIALS	13	Earliest	Now less Sanker Panasonic
AIST	- 11	patent	Now less Sinker Parlasonic
SANKEN ELECTRIC	10	applicants 2 2 3 1 1	
NGK INSULATORS	9	2 4 1 1	active INISSAN MITSUBISHI MITSUBISHI MEIDEN
NGK SPARK PLUG	8	2 1 1 3	`
SAMSUNG ELECTRONICS	8	2 1 1 4	
MITSUBISHI ELECTRIC	451	1 1 3 2 1 2 1 1 9 29 35 48 32 67 54 52 46 47 20	MITSUBISHI ELECTRIC
HITACHI	102	1 3 2 1 1 2 4 4 4 17 23 20 7 7 5	→ HITACHI
roshiba	38	3 1 1 3 5 7 4 4 3 6 1	TITIAOTII
DENSO	36	3 4 7 1 1 4 5 2 2 6	
CREE / WOLFSPEED	21	1 2 3 3 4 4 1 2	
CRRC	9	3 1 1 2 1	
-UJI ELECTRIC	119	IP I I 9 11 17 20 5 10 15	→ ROHM
ROHM	100	transfer 2 1 3 4 13 10 12 9 11 14 10 11	SEMICONDUCTOR SEMICONDUCTOR
TOYOTA MOTOR	71	2 2 1 2 4 2 2 6 4 4 3 4 4 20 11	TOYOTA A BABA
ABB	37	1 1 2 9 8 12 1 1	TOYOTA A D D
GENERAL ELECTRIC	34	1 1 1 2 2 1 5 4 10 2 2	ABB
ROBERT BOSCH	17	2 1 1 2 8 1 1	
ZHEJIANG UNIVERSITY	8	4 2 1 1	
MURATA MANUFACTURING	8	1 1 2 1 2	
DELTA ELECTRONICS	19	1 2 1 3 6 2 4]
ANGZHOU GUOYANG ELECTRONIC	16	2 7 6 1	
MIDEA	56	Knowmade © 2021	Newcomers in ON A DELTA
KI'AN JIAOTONG UNIVERSITY	12	3 1 4 4	Newcomers in
AUDI	9	4 4 1	the WBG Power
DANFOSS	8	1 4 3	
NORTH CHINA ELECTRIC POWER UNIVERSITY	8	2 2 2 2	Module Patent Danfold Midea
ON SEMICONDUCTOR	8	1 1 3 2	Landscane
DENKA	8	1 1 5	ShinDengen / CETC
SHINDENGEN ELECTRIC MANUFACTURING	20	9 10 1	Jim Bengen
HUANGSHAN UNIVERSITY	9		

WBG power modules vs. SiC MOSFET



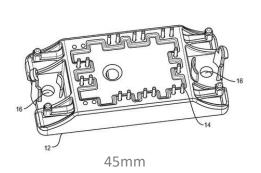


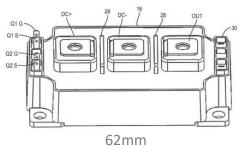


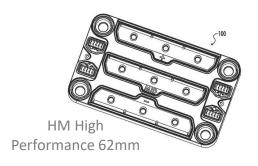
Pure WBG player: Cree/Wolfspeed's patents

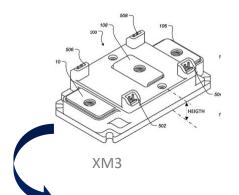
Wolfspeed. | A CREE COMPANY

Cree/Wolfspeed is a fairly new IP player in the Power Module Patent Landscape, which started actively filing patents after the acquisition of **Arkansas Power Electronics International (APEI)**.



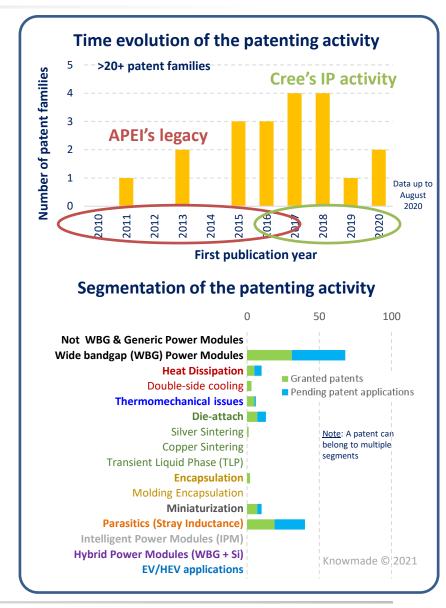






> 10 related documents (design, patent applications, etc.)

- Highly optimized to achieve the maximum performance out of all sizes of commercially available 650-1700V SiC MOSFETs
- Capability to carry high currents (300 to > 600 A) in a small footprint (53 mm x 80 mm)

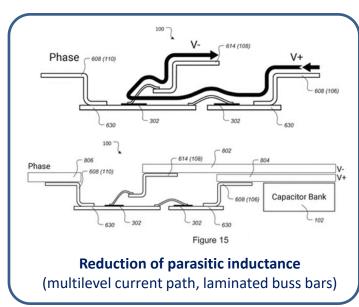


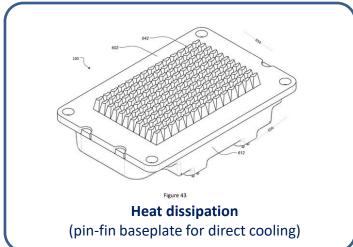


Pure WBG player: Cree/Wolfspeed's patents

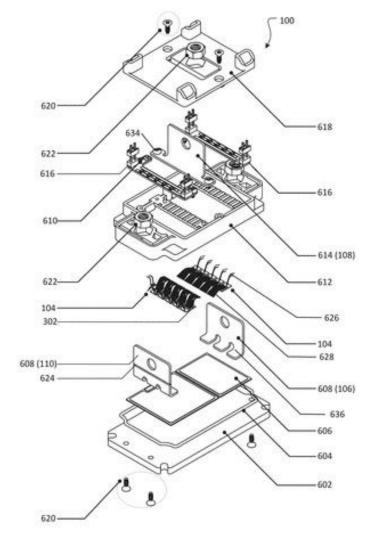


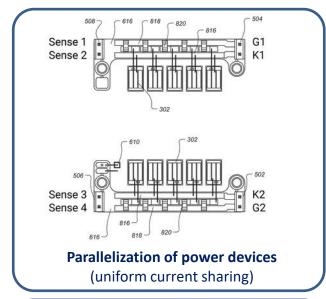
A CREE COMPANY

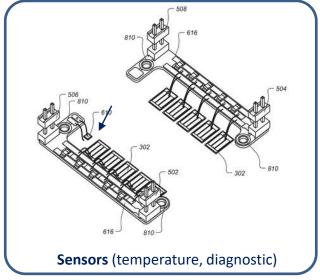




High-power Low-inductance Fast-switching power module



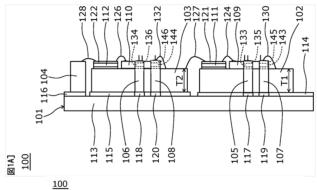


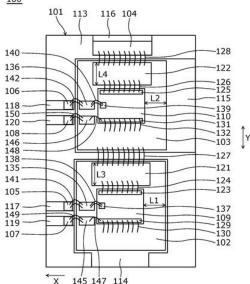


Examples of recent GaN power module patents (2020)

Panasonic

- Heat dissipation at high-power/high-speed
- High-frequency characteristics (stray inductance)
- o Small-size GaN power chips

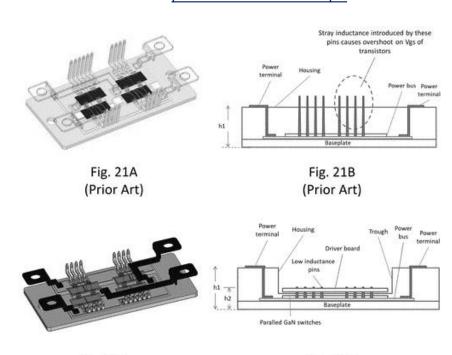






Low-profile, low-inductance power modules for ultra-fast GaN-HEMTs:

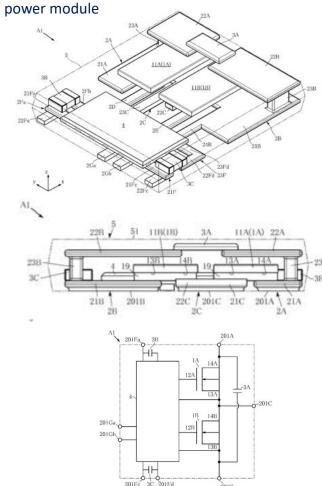
- o Low-inductance terminals for gate and source-sense connections
- o Low inductance gate drive loop
- Low inductance path for high-frequency current and balance inductances of the power commutation loops for each switch



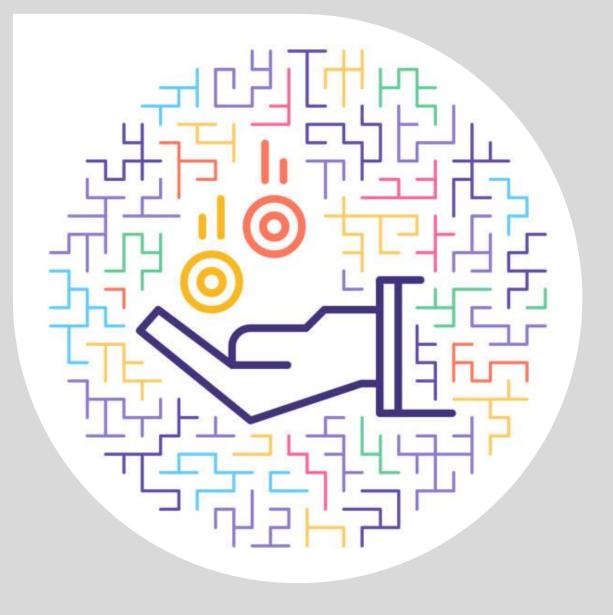




Suppression of surge voltage in a half-bridge nower module





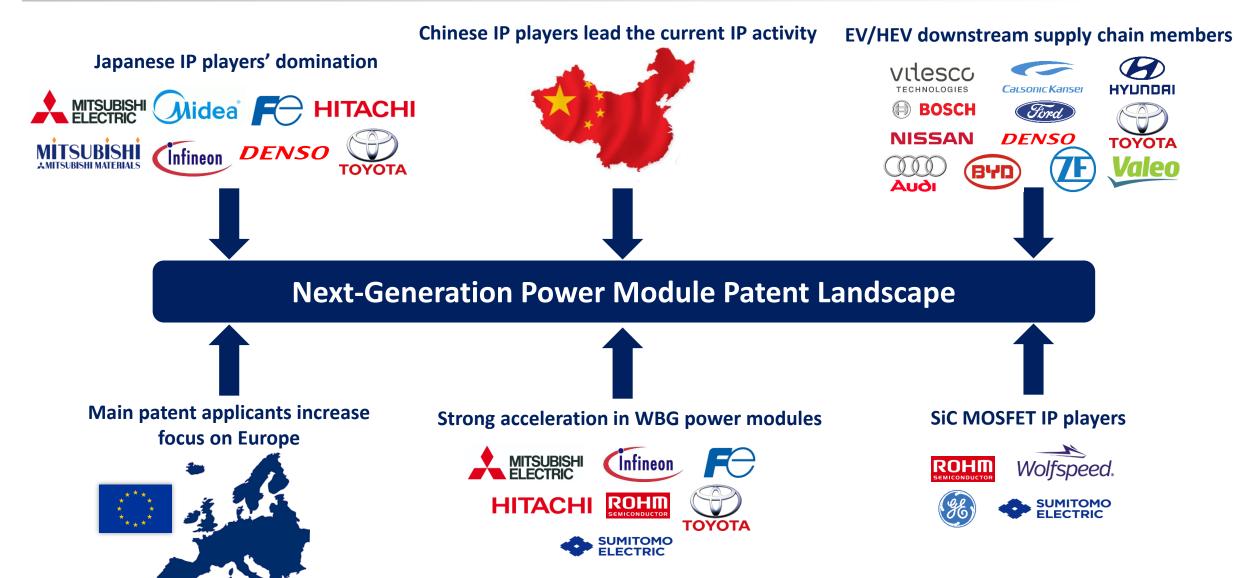


Conclusion



Conclusions

Next-Generation Power Module Patent Landscape

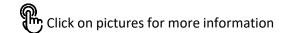


THANK YOU!

Contact:

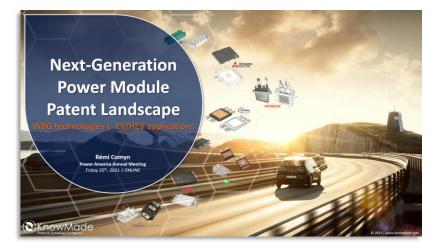
Rémi Comyn, Technology & Patent Analyst remi.comyn@knowmade.fr www.knowmade.com

Released and Upcoming Power Electronics Reports:



Next-Generation Power Modules (2021)

Patent Landscape Analysis



Power SiC (2019)

Patent Landscape Analysis



Next Generation SiC Power Devices (2021)

Patent Landscape Analysis



Power GaN (2019)

Patent Landscape Analysis



Transphorm IP Portfolio Analysis Navitas IP Portfolio Analysis

•••







KNOWMADE PURPOSE

Turning patents and scientific information into business-oriented report for decision makers working in R&D, Innovation Strategy, Intellectual Property, and Marketing

Competitive landscape | Technology trends | Opportunities / Risks | R&D and IP strategy







Intellectual Property

Patent your inventions

Assert your patents and defend your position in case of licensing/litigation

Evaluate the risks to infringe patents

Prior art search, Freedom-to-operate analysis, Patent invalidation, Evidence of use, Patent valuation Understand, anticipate and evaluate the competitive landscape and current technology developments

Patent landscape, Monitoring service,
IP due diligence

Innovation Strategy

Improve your R&D and IP strategy

Identify and get access to external innovation

Technology scouting, Scientific literature analysis



MAIN FIELDS OF EXPERTISE

Communication

> RF, microwave, mm-wave

Datacom & Photonics

> Front end modules

> Antenna & Networks



Advanced Packaging Innovative Materials AI & Computing

Energy

- Power electronics
- Batteries & Fuel-cell
- > Power management
- ▶ PV



MEMS, Sensors & Optoelectronics

- Micro-systems
- Sensors & Imaging
- ➤ Lighting & Display

Life Sciences & Healthcare

- MedTech
- Microfluidics
- ➤ Biotech & Pharmaceutics
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